John Avangy 38 hot smed 8

modules

1024 BIPOLAR READ ONLY MEMORY IM5603

FEATURES

- Programmable—No additional masks
- High Speed: Access time-40 nsec.
- High Fan-out-20 mA
- DTL/T2 L Compatible-Inputs one T2 L load
- OR-Tie capability-open collector outputs
- Simple Memory Expansion-chip enable Input
- Standard Packaging-16 pin dual-in-line/flat pack

GENERAL DESCRIPTION

The Intersil IM5603 integrated circuit is a high speed, electrically programmable, fully decoded T²L Bipolar 1024-bit road only memory, organized as 256 words by 4 bits. On chip address decoding, along with chip enable, and uncommitted collector outputs provide for simplified memory expansion. The memory is fabricated with all logic level zeros (low); logic level ones (high) can be electrically programmed in the selected bit locations through proper addressing. The same address inputs are used for both programming and reading. This memory is compatible with other DTL and T2 L circuits.

APPLICATIONS

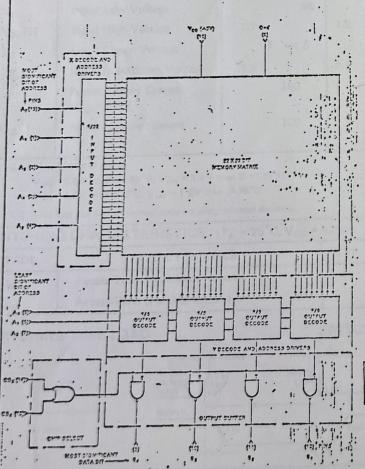
- Code Conversion
- Microprogramming
- Logic Implementation
- · Arithmetic Functions

OPERATION

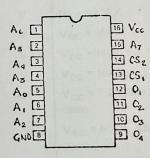
Ones can be programmed into the memory by selecting the desired word, using the five address inputs and applying a high current pulse to the output for the desired bit. The chip enable input must be high when the programming pulse is applied. After the program pulse is removed, the bit is checked. If it is still a zero, another program pulse is applied. If it is a one, the programming of that bit is complete. The programming can be easily automated for volume production. Complete programming information is contained in the "Intersil Electrically Programmable ROM Manual" available on request.

To read the memory the enable input is held low. The outputs then correspond to the data programmed in the selected word. With the enable input high, all outputs are floating.

LOGIC DIAGRAM

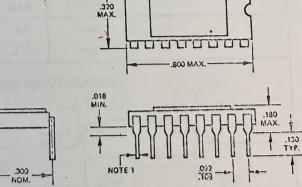


CONNECTION DIAGRAM



Pin 1 is designated either by a dot or a notch.

PACKAGE OUTLINE



NOTE: Board drilling dimensions will equal standard practices for .020 diameter lead.

INTERSIL MEMORY CORPORATION 10900 N. TANTAU AVE., CUPERTINO, CA. 95014

(408) 257 5450 TWX 910 338 0276



ABSOLUTE MAXIMUM RATINGS

Supply Voltage Input Voltage Applied Output Voltage Applied Output Voltage Applied (Programming Only)

+7.0V -1.5V to +5.5V -0.5V to $+V_{CC}$ Current into Output (Programming Only) Operating Temperature

Storage Temperature

250mA -55°C to +125°C 0°C to +75°C -65°C to +150°C

40V DC CHARACTERISTICS $(T_A = -55^{\circ}C \text{ to } +125^{\circ}C, V_{CC} = 5.0V \pm 10\%), (T_A = 0^{\circ}C \text{ to } +75^{\circ}C, V_{CC} = 5.0V \pm 5\%)$

SYMBÒL	CHARACTERISTICS	Limits -55°C to +125°C		Limits 0°C to +75°C MIN MAX		UNITS	CONDITIONS	
		MIN	MAX	MIN	-1.00	mA	V _{CC} = MAX, V _A = 0V	
IFA	Address-Input Load Current		-1.00				$V_{CC} = MAX, V_E = 0$	
I _{FE}	Chip Enable-Input Load Current		-1.00		-1.00	mA		
IRA	Address-Input Leakage Current		100		60	μΑ	$V_{CC} = MAX, V_A = 4.5V$	
IRE	Chip Enable-Input Leakage		100	1100	60	μΑ ;	$V_{CC} = MAX, V_E = 4.5V$	
I _{OLK}	Current Output Leakage Current	400	100		100	μΑ	$V_{CC} = V_O = MAX V_{CC}$, VE = 2.0V	
lork	Output Leakage Current		100		100	μΑ	V _{CC} = V _O = MAX V _{CC} , V _E = Word containing a "1" bit is selected. See Note 2.	
V _{OL}	Output Low Voltage		0.4	is u	0.45	V.	V _{CC} = MIN, I _{OL} = 20 mA, VE = 0. Word containing a "0" bit is selected.	
V	Input Low Voltage		.85	BE &	.85	V	V _{CC} = MAX	
V _{IL}		1.7		1.8	Han.	V	V _{CC} = MIN	
V _{IH} (1)	Input High Voltage	1.7	-1.5		-1.5	V	V _{CC} = MIN, I _{IN} = -10 mA	
Vc	Input Clamp Voltage		-1.3	5.5		V	V _{CC} = MAX, I _{IN} = 1.0 mA	
BVIN	Input Breakdown Voltage	5.5		5.5	100	a transfer	$V_{CC} = 7.0V$. All inputs	
IBV	Power Supply Current V _{CC} = 7.0V		160		160	mA	open open	
Icc	Power Supply Current		100		125	mA	V _{CC} = MAX. All inputs open	

NOTE 1: VIH Limits @ 25°C

 V_{IH} = 2.0V max @ -55°C; V_{IH} = 1.4V max @ +125°C

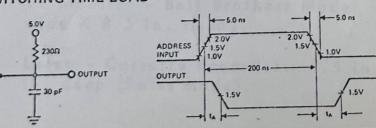
V_{IH} = 1.9V max @ 0°C; V_{IH} = 1.6V max @ 75°C

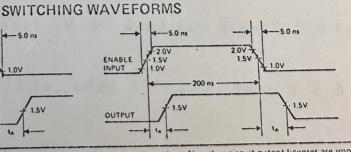
NOTE 2: This test can be performed only on programmed devices.

	0	01/1
THE PARTY OF THE P	IT - 25	$C V_{} = h(V)$
SWITCHING CHARACTERISTICS	114 - 23	C, VCC 3.011
SWITCHING OIL HIN TO I		

SYMBOL	CHARACTERISTICS	TYP	MAX	UNITS	国工程(国) (3.3
t _A	Access Time (via address inputs)	40	60	nsec	
t _A	Access Time (via chip enable)		30	nsec	的 一

SWITCHING TIME LOAD





Intersil cannot assume responsibility for use of any circuitry described other than circuitry entirely embodied in an Intersil product. No other circuit patent licenses are implied.